

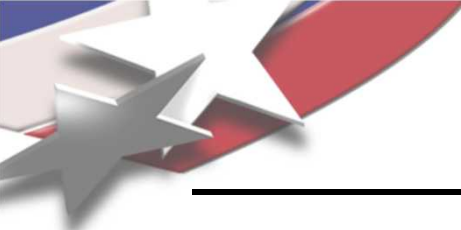
MEMS Ohmic Latching Relay

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Presentation Outline

- **Comparison with COTS latching relays**
- **Design and fabrication**
- **Shock testing**
- **Radiation testing**
- **Frequency performance**
- **Contact metallurgy**



Comparison versus COTS parts

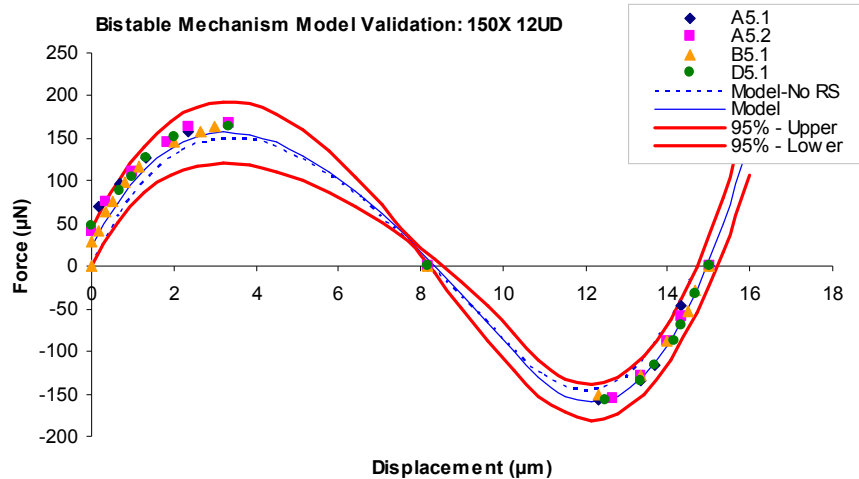
- **Pro's of MEMS relay**

- Custom layout (multiple pole, multiple throw)
- Low energy consumption (~150 mW switch power for ~0.25 ms)
- Smaller total volume
- Smaller electrical length at high frequency
- Shock and radiation hard
- No chatter and fast switching (<0.5 ms)
- Longer life demonstrated on several parts

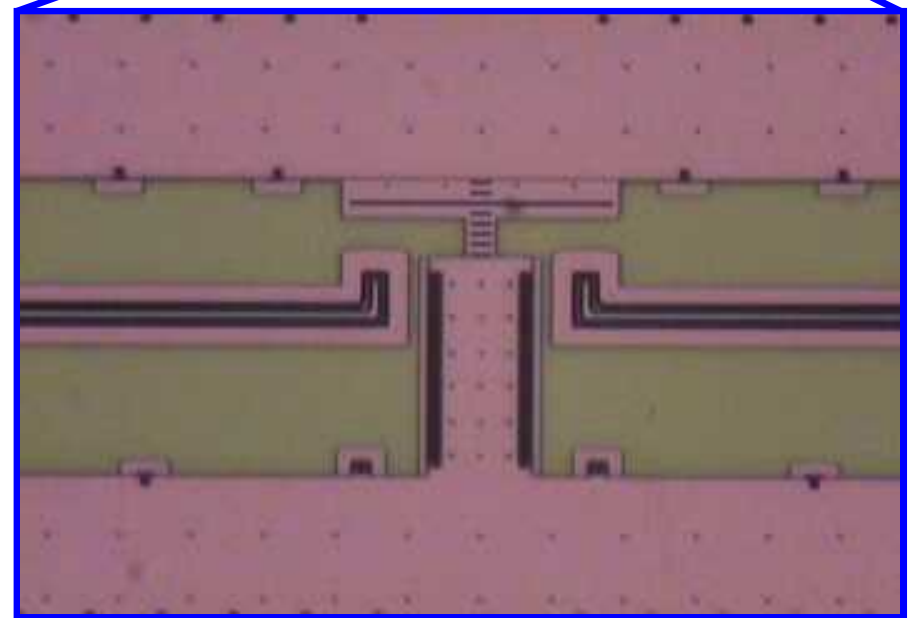
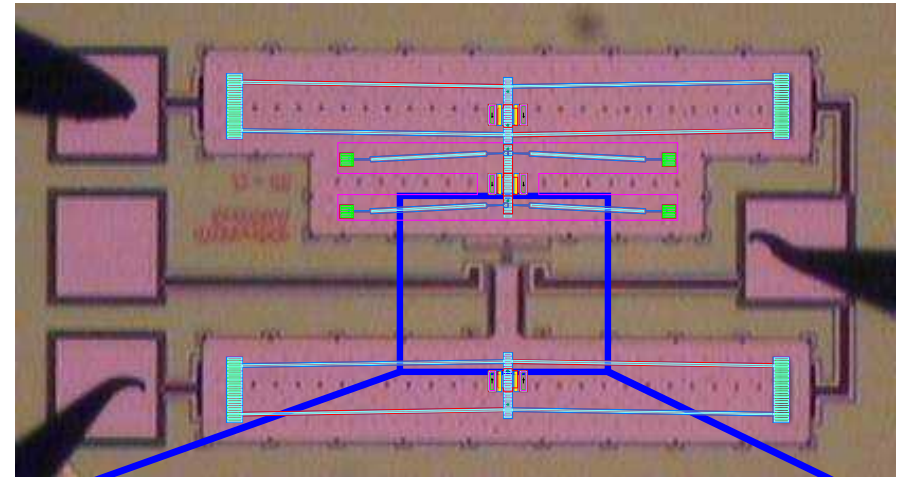
- **Con's**

- Not available for \$6.50 each in orders of 1M parts
- Resistance/power handling of metal contact – practical below 20 mA at this time (can be engineered to be larger)
- Currently, resistance through switch is greater than 5Ω

Latching Relay Design

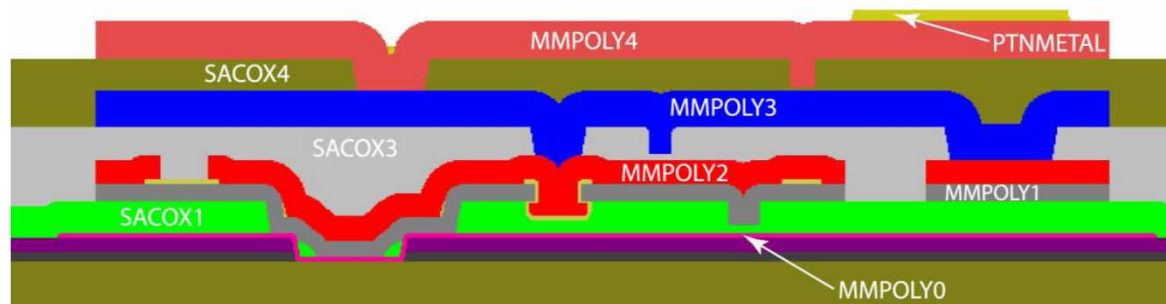
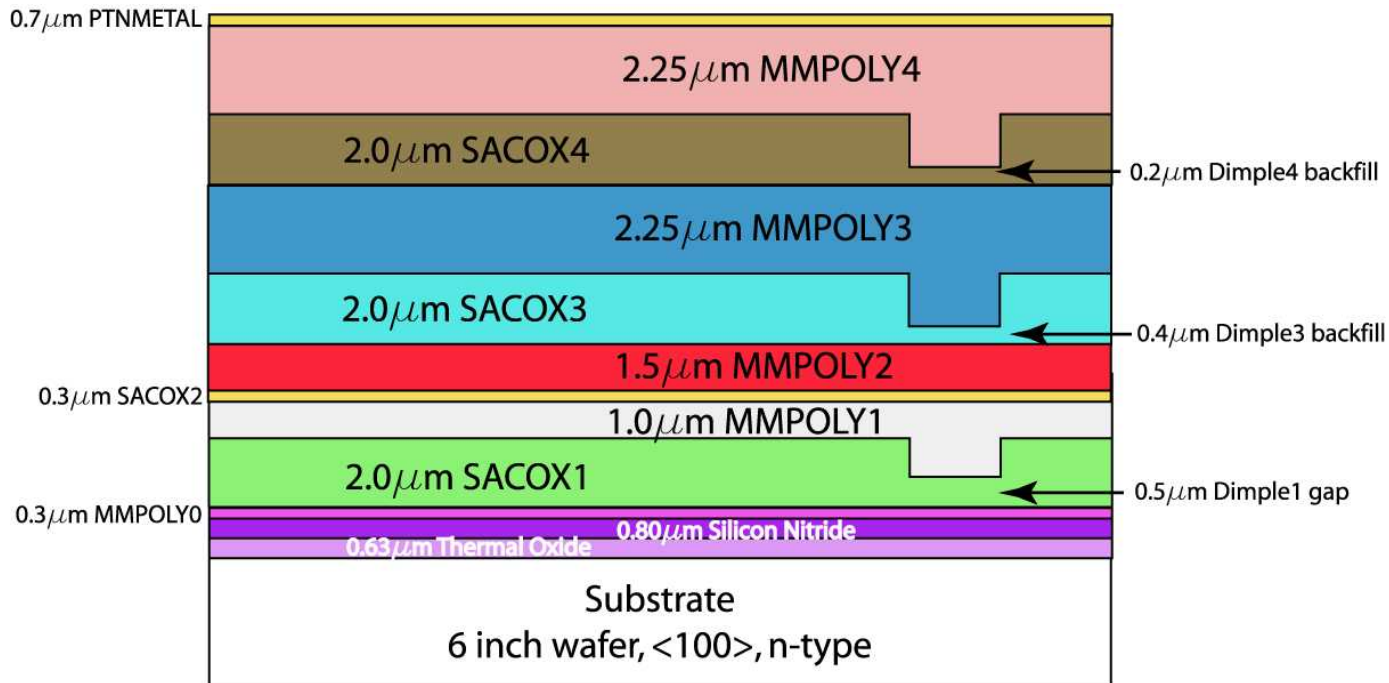


- **2 stable equilibrium positions**
- **1 unstable equilibrium position**
- **Can design mechanism for unique response curves**



Latching Relay Fabrication

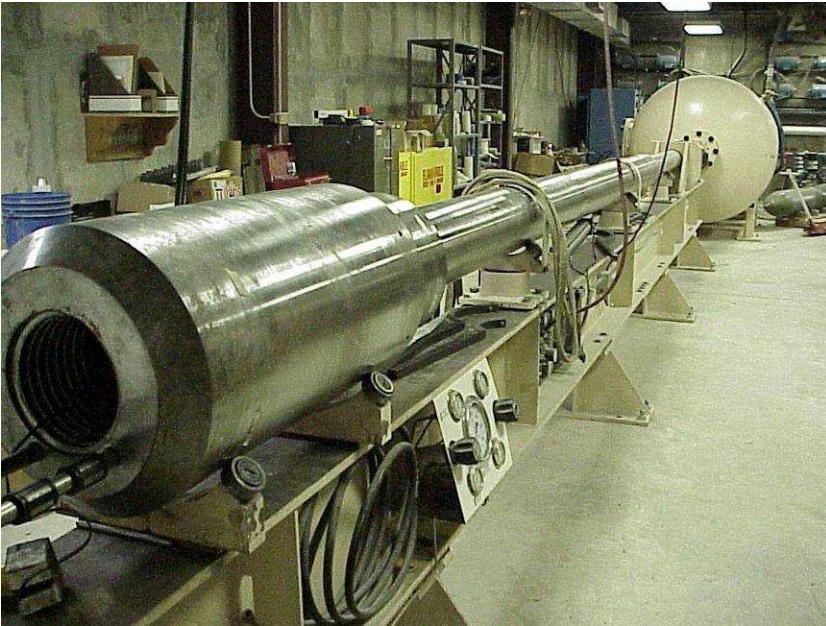
SUMMiT™



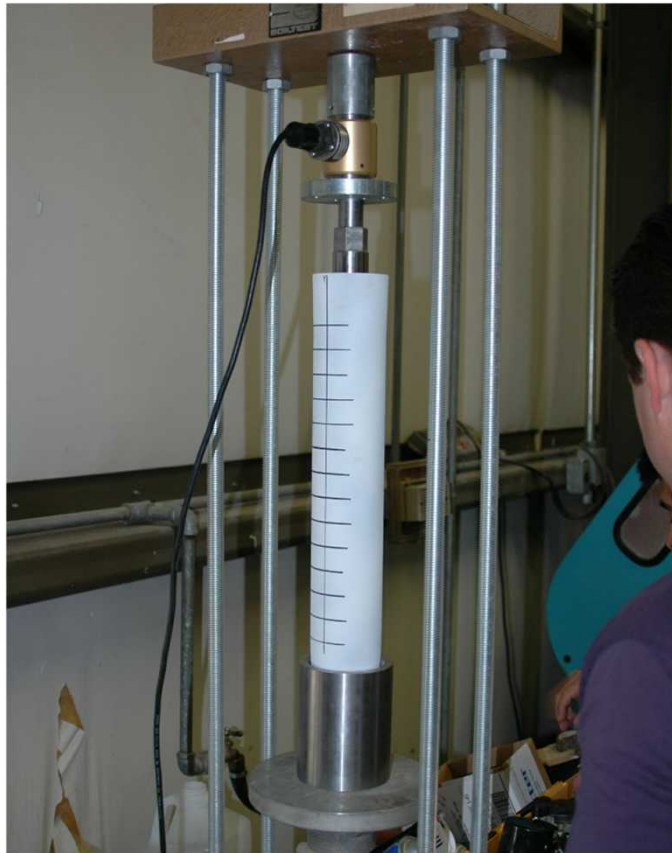
<http://www.MEMS.Sandia.gov/>

Penetrator Gun and Target

- Performed at the Waterways Experiment Station in Vicksburg, MS (Army Corps of Engineers)

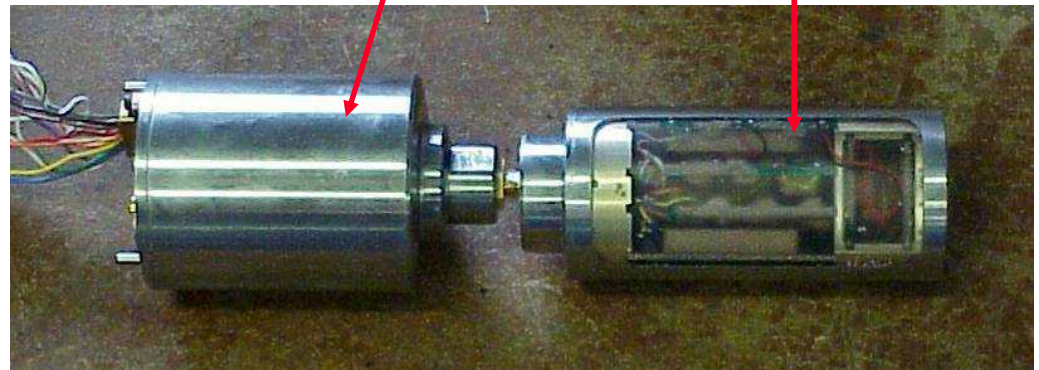


Penetrator Test Setup

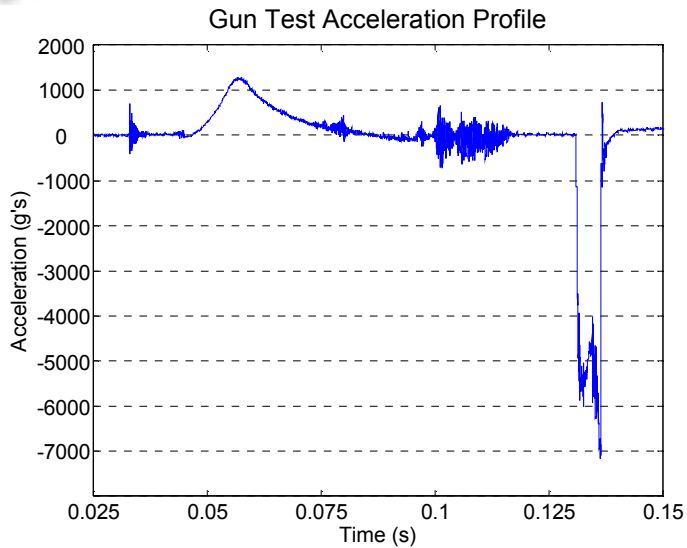


- **Penetrator**
 - 22" long, 3" diameter
 - 13.7 lbs.

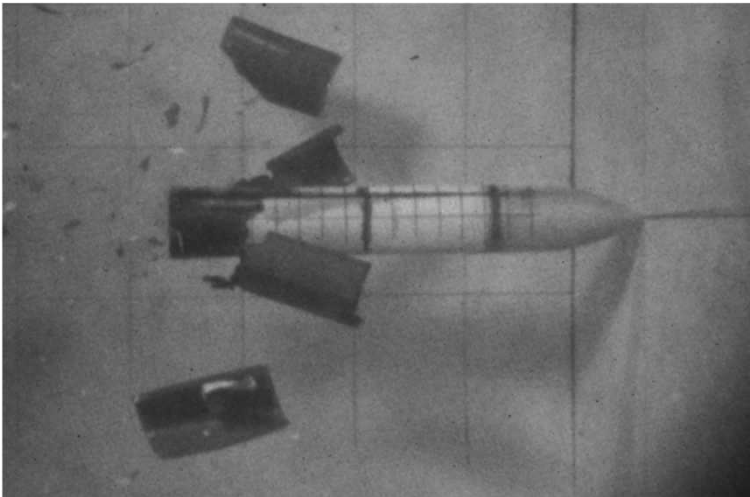
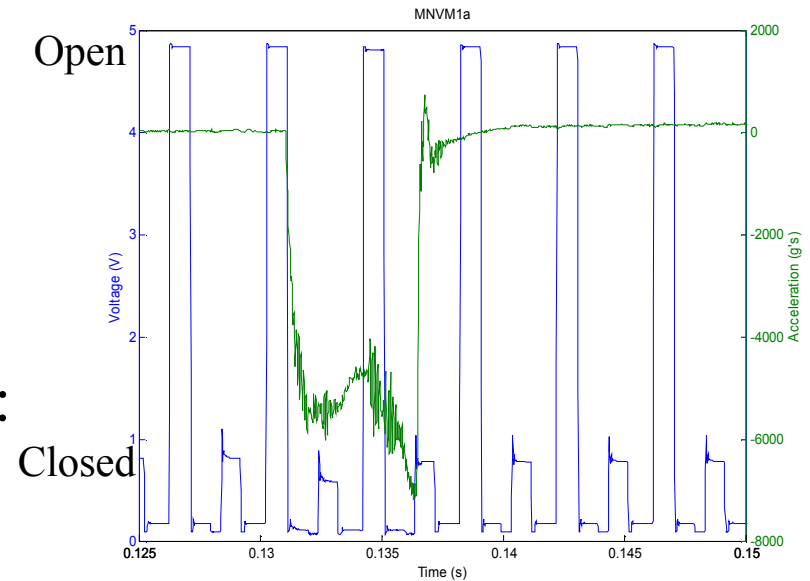
- **Housing mates to MDES and assemblies in penetrator**
- **MDES unit:**
 - Power
 - Ground
 - Analog/digital inputs
 - Records analog/digital outputs



Penetrator Test Results

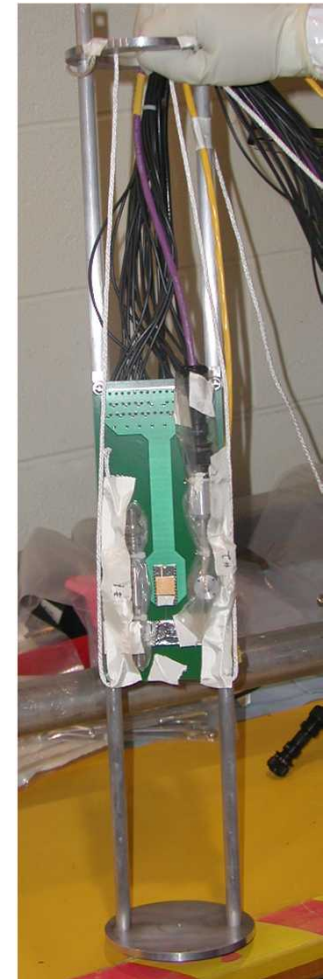
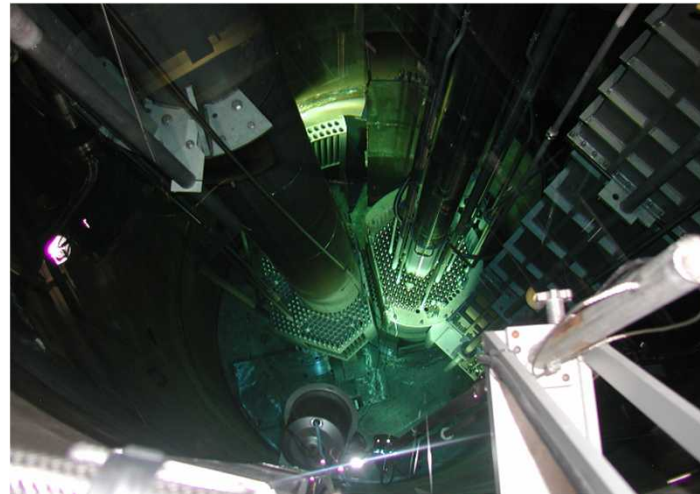
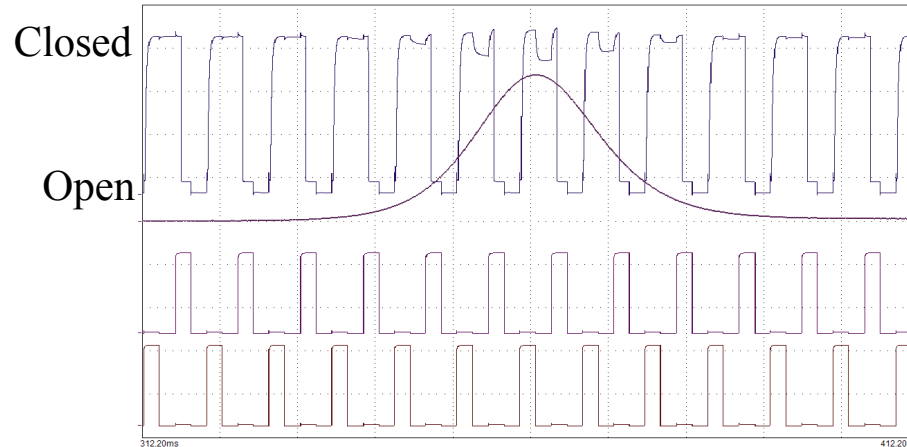


Duration:
> 5.5 ms
Ave. accel.:
~5500 g's
Max. accel.:
> 7200 g's



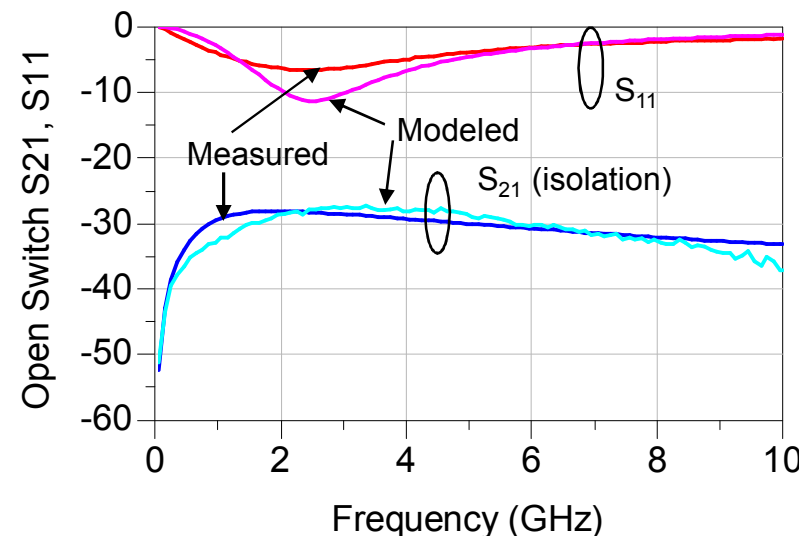
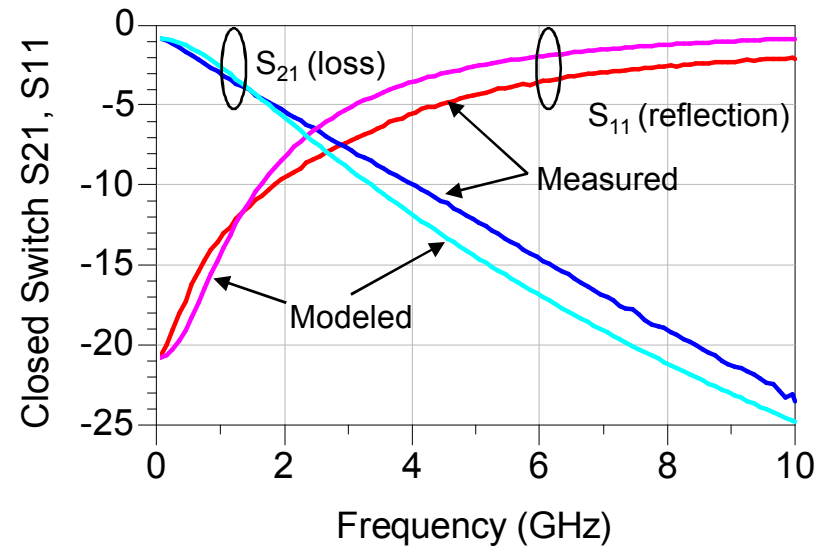
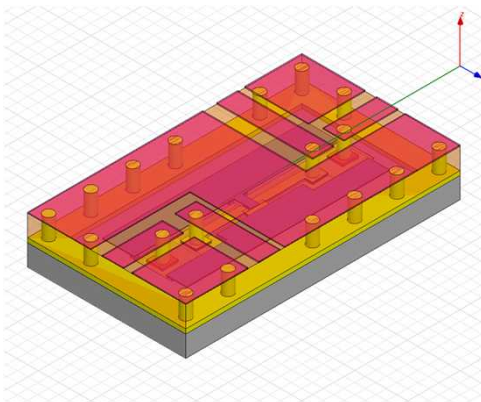
ACRR Radiation Testing

- Operated through
 - 16.5 Mrad(Si) total dose at steady-state
 - 100 Mrad(Si)/s peak dose rate from pulse
 - 1×10^{16} n/cm² max fluence



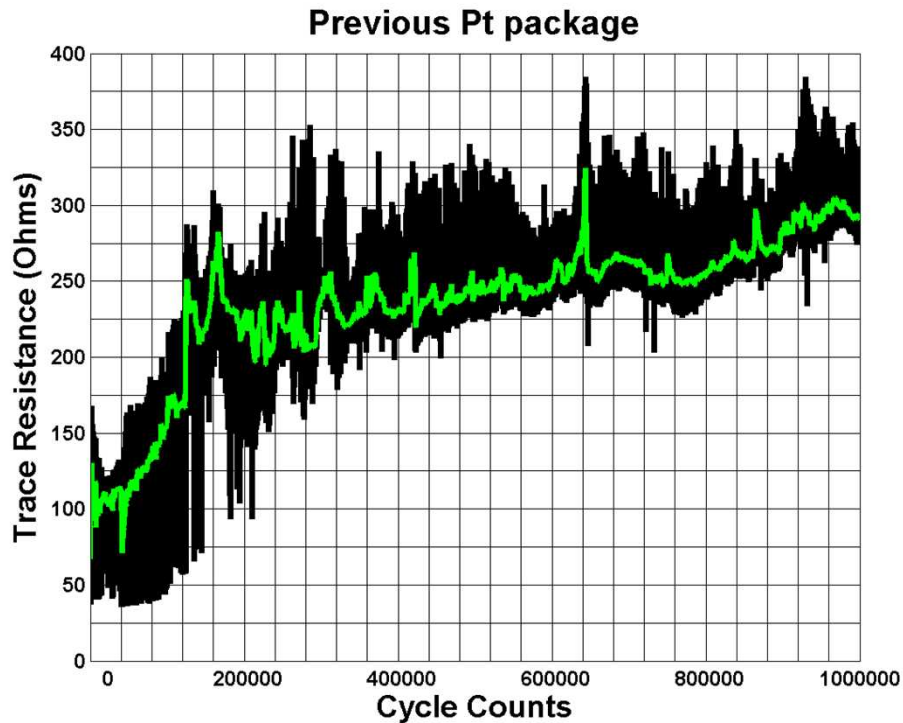
RF Measurements

- **Gold-contact SPST tested using RF probes**
 - Using old DC design
 - Wirebonds ~2 mm long (~2 nH)
- **SPST switch has 3 dB insertion loss and 32 dB isolation at 1 GHz**
 - Substrate capacitance is major contributor to insertion loss and off-state resonance
 - Simple redesign of trace would greatly improve performance

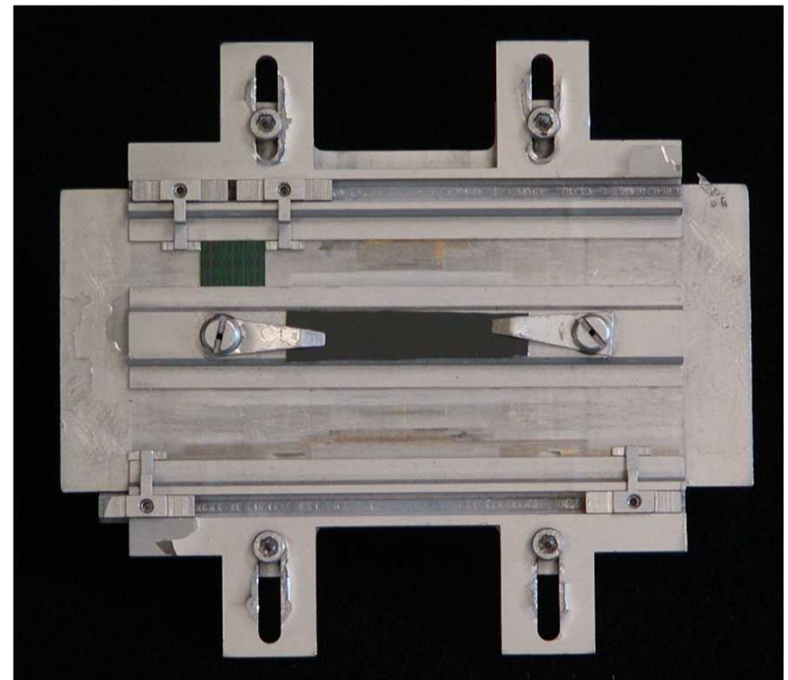


Contact Metallization

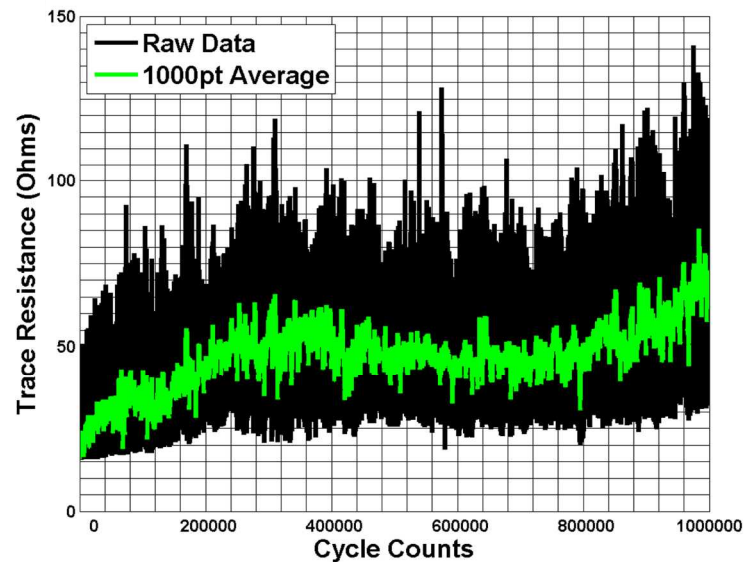
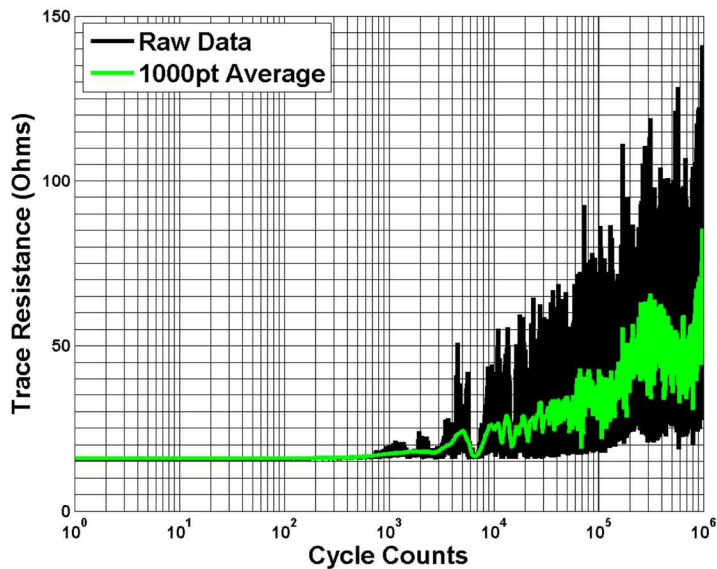
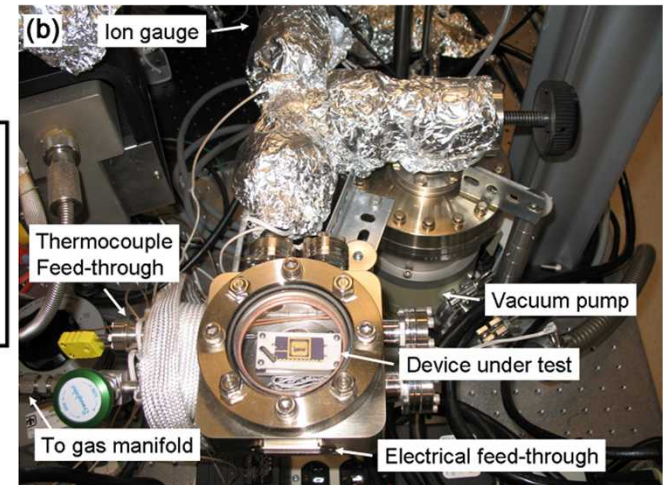
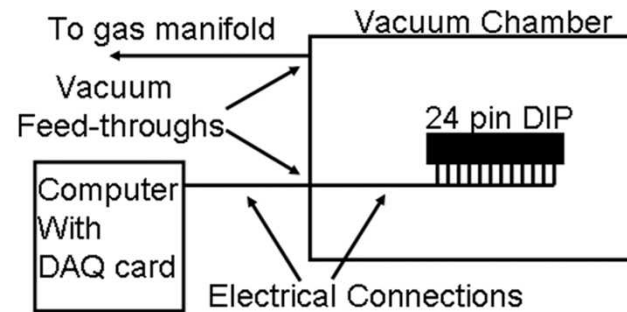
- Au selected as initial contact metal – too sticky
- Platinum selected as candidate (harder material)
- Contact is reliable but resistance is high and increases dramatically with cycle count.



Pt Contact, O₂ Plasma cleaned,
Hermetic package in N₂ atmosphere

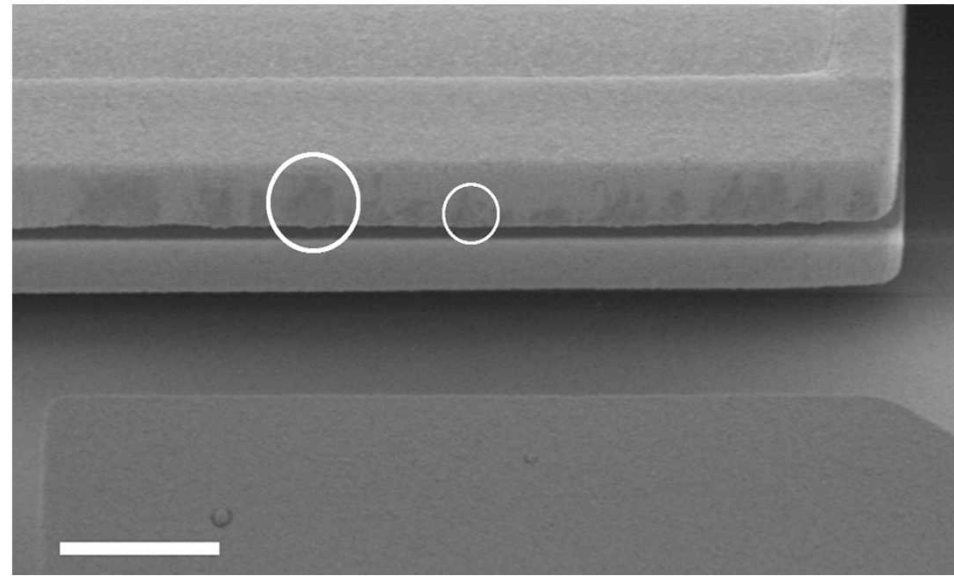
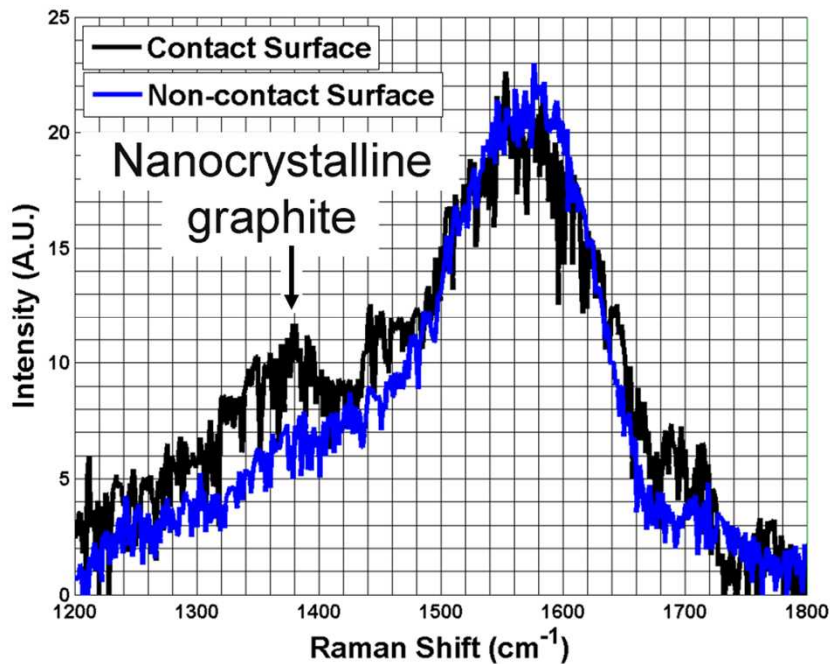


Clean Environment



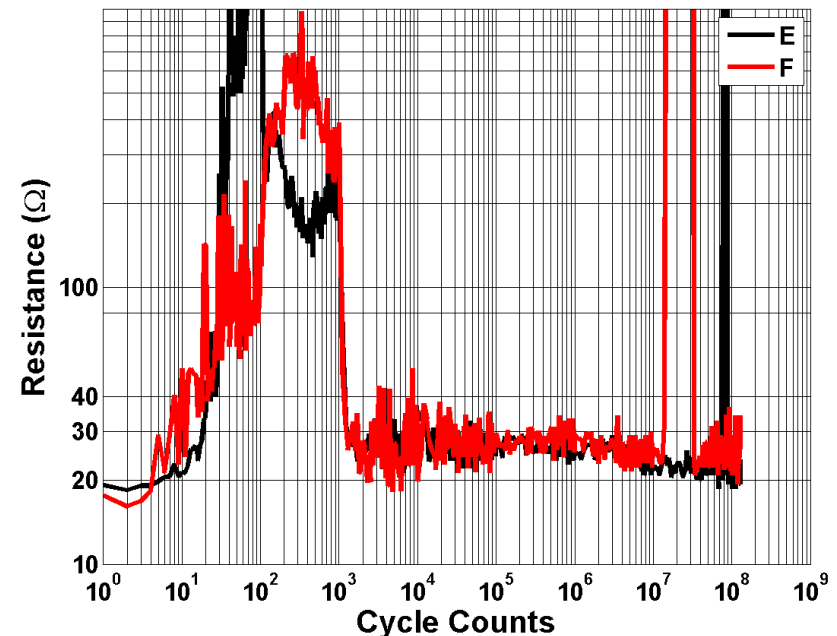
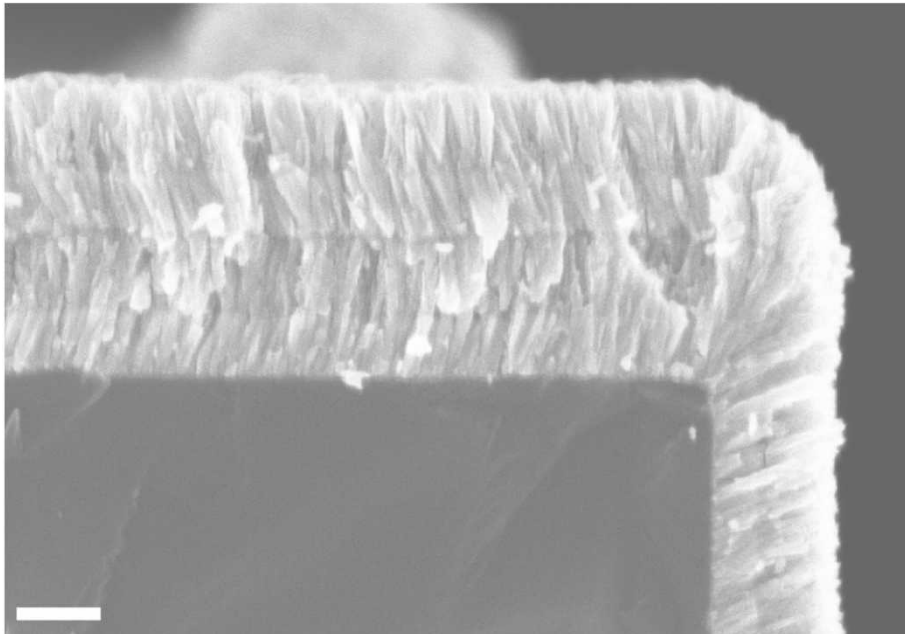
Contact Contamination

- Inspected contact surfaces with SEM
- Used Raman spectroscopy to analyze surfaces
- Build-up is present under mechanical cycling only and is not due to hot or cold switching



Ruthenium Oxide Metallization

- Literature suggests that transition metal oxides prevent accumulation of friction polymer (Rh_2O_3 , RuO_2 , IrO_2 , ReO_3)
- Proven in commercial reed relays (low force, high cycle count macro-scale relays)
- Ruthenium Oxide selected as candidate metal.



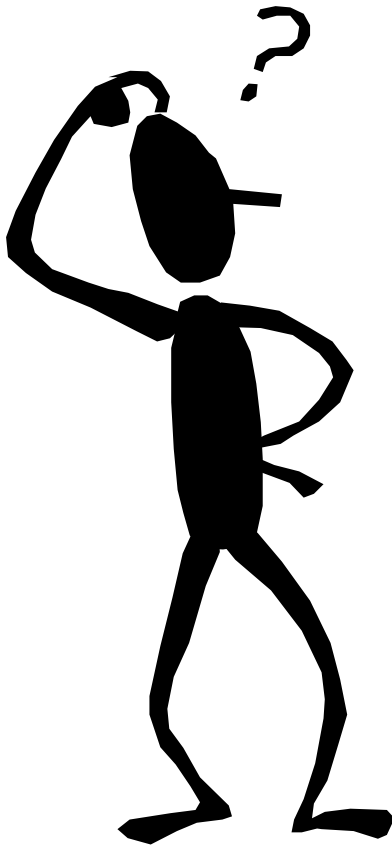
- Overall, MEMS latching relays are TRL 4
- TRL limited to 4 by contact metallurgy
- Radiation and shock testing increased TRL to ~6
- Designing relays for larger bandwidth
- Can custom design to multiple pole and throw
- Can be integrated with other components to provide new or improved functionality over existing COTS parts
- Tunable antennas ???
- Switching COM bands in multi-RF front ends ???

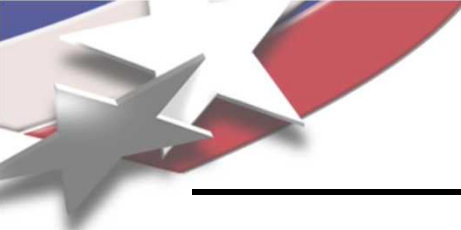


Acknowledgments

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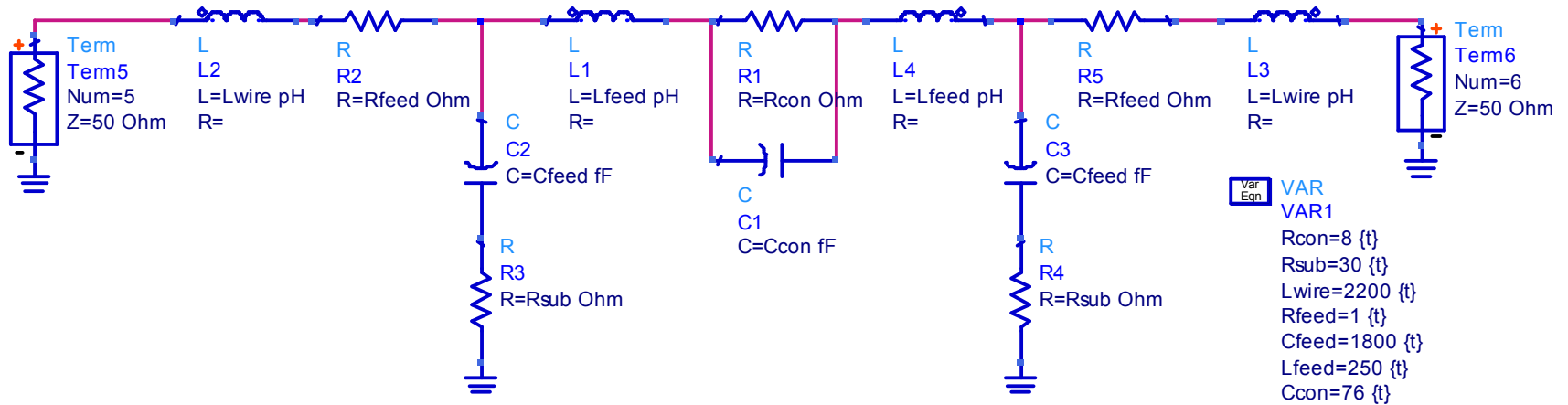
Questions





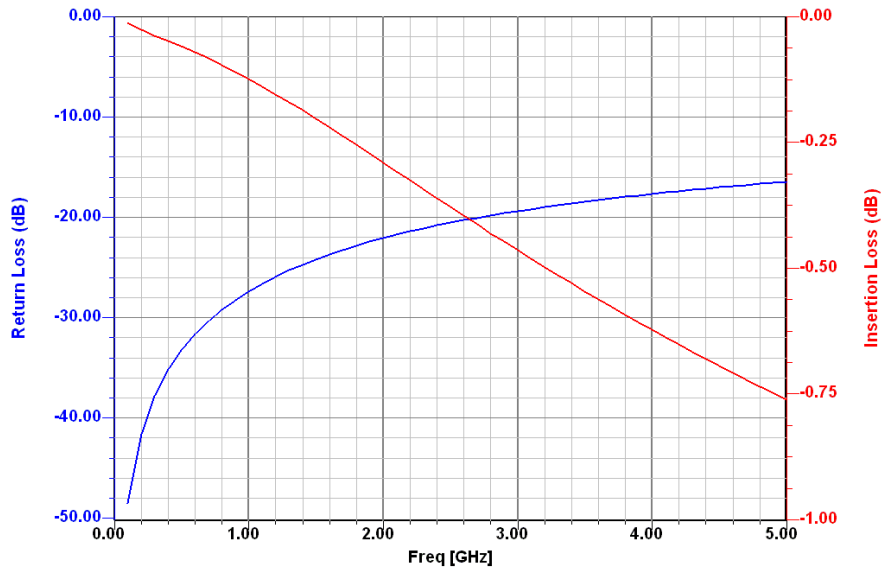
Extra slides

RF Measurements

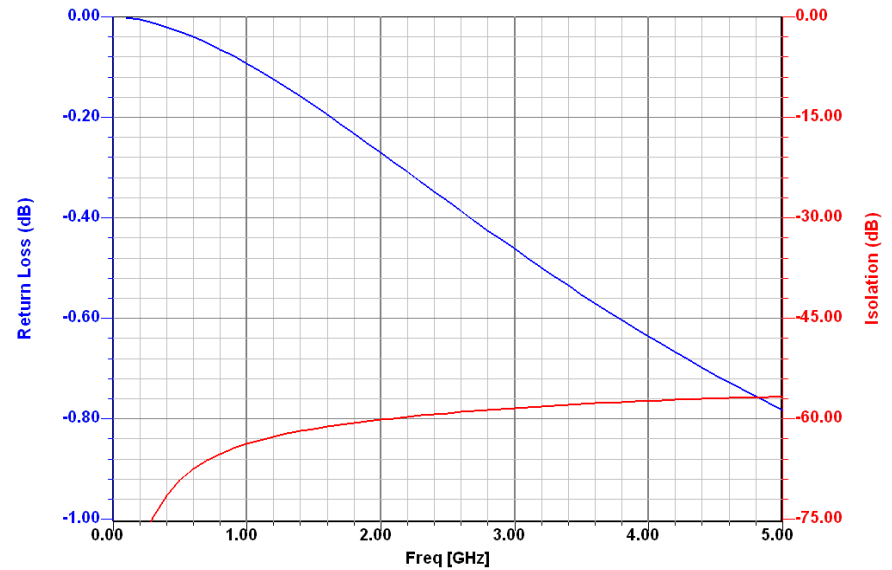


Equivalent circuit model for latching relay

RF Measurements



Relay Closed



Relay Open